

Amendments to the Drawings:

Please add the one sheet of drawings showing FIG. 1 as enclosed herewith.

Amendments to the Specification:

Please amend the Specification as follows:

On Page 1, above line 1, please insert the following paragraphs:

--CROSS REFERENCE TO RELATED APPLICATIONS

Priority is claimed under 35 U.S.C. 119 of German Patent Application No. 199 60 823.7 filed December 16, 1999. Priority is claimed under 35 U.S.C. §120 of U.S. Patent Application Serial No. 09/716,708 filed November 20, 2000.--

Please amend page 16 of the Specification between lines 18 and 19 to recite the new paragraphs:

--BRIEF DESCRIPTION OF THE DRAWINGS

FIG. 1 shows a silicon single wafer according to the invention.--

Please amend page 17 of the Specification between lines 7 and 8 to recite the new paragraph:

--Referring to FIG. 1, the semiconductor wafer 1 preferably has a front surface 3, a back surface 5, an imaginary central

plane 7 between the front and back surfaces, and a circumferential edge 2 joining the front surface 3 and the back surface 5. The terms "front" and "back" in this context are used to distinguish the two major, generally planar surfaces of the wafer 1. There is an epitaxial layer 9 on the front surface 3 of the pretreated semiconductor wafer 1.--